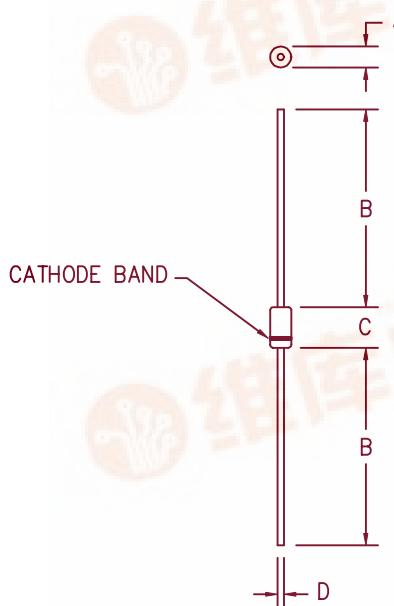


5 Amp Schottky Rectifier

MS508 — MS510



Dim.	Inches		Millimeter		Notes
	Minimum	Maximum	Minimum	Maximum	
A	.188	.260	4.78	6.50	Dia.
B	1.00	---	25.4	---	
C	.285	.375	7.24	9.52	
D	.046	.056	1.17	1.42	Dia.

PLASTIC D0201AD

Microsemi
Catalog Number

Working
Peak Reverse
Voltage

Repetitive
Peak Reverse
Voltage

MS508 80V
MS509 90V
MS510 100V

- Schottky Barrier Rectifier
- Guard Ring Protection
- Low power loss, high efficiency
- High surge capacity
- V_{RRM} 80 to 100 Volts

Electrical Characteristics

Average forward current
Average forward current
Maximum surge current
Max peak forward voltage
Max peak forward voltage
Max peak reverse current
Typical junction capacitance

| $I_F(AV)$ 5.0 Amps
| $I_F(AV)$ 5.0 Amps
| I_{FSM} 250 Amps
| V_{FM} .60 Volts
| V_{FM} .80 Volts
| I_{RM} 250 μ A
C_J 280 pF

T_A = 131°C Square wave, R_{θJL} = 11°C/W, L = 1/8"
T_A = 116°C Square wave, R_{θJL} = 14.7°C/W, L = 3/8"
8.3ms, half sine, T_J = 175°C
I_{FM} = 5.0A; T_J = 175°C*
I_{FM} = 5.0A; T_J = 25°C*
 $V_{RRM}, T_J = 25^\circ C$
 $V_R = 5.0V, T_J = 25^\circ C$

*Pulse test: Pulse width 300 μ sec, Duty cycle 2%

Thermal and Mechanical Characteristics

Storage temperature range
Operating junction temp range

T_{STG}

-55°C to 175°C

Maximum thermal resistance

T_J

-55°C to 175°C

Weight

L = 1/8" R_{θJL}
L = 3/8" R_{θJL}

11°C/W Junction to lead
14.7°C/W Junction to lead
.032 ounces (1.0 grams) typical

MS508 – MS510

Figure 1
Typical Forward Characteristics

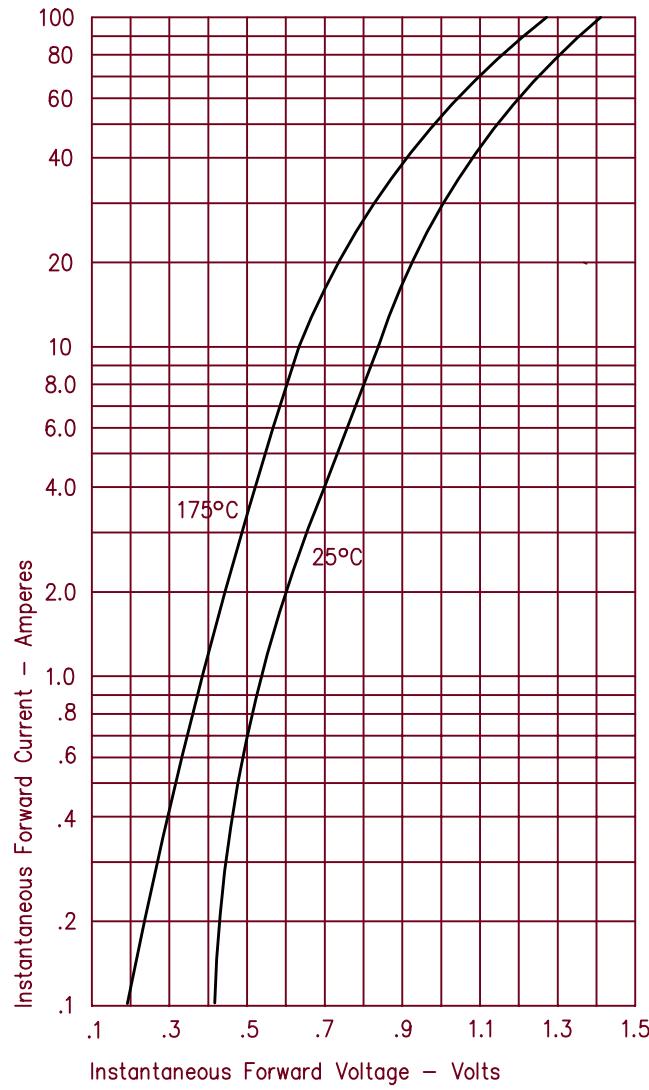


Figure 3
Typical Junction Capacitance

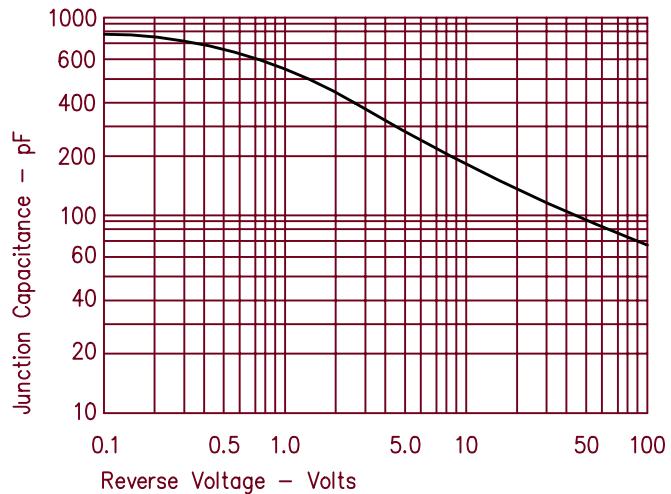


Figure 2
Typical Reverse Characteristics

